

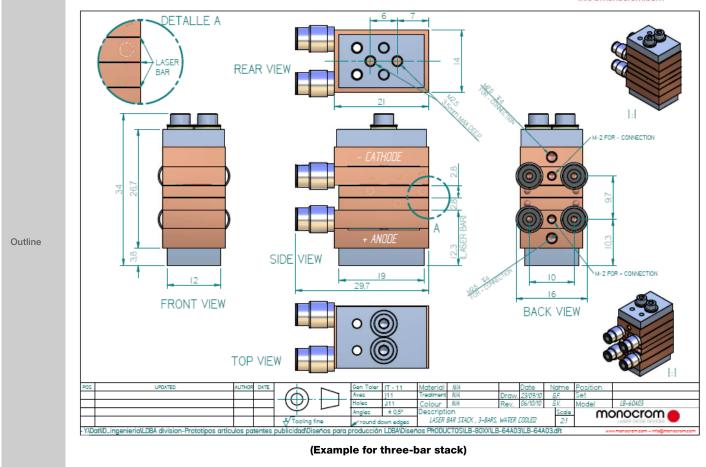
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	Barcelona Spain www.monocrom.com					
Product Division	LDBA Laser Diode Bar Assemblies					
Product	LB-80A10-60QCW-2					
Description	LBS 60em., 10 bars, 808 +/- 3 nm @ 270W/bar up to 2700 W QCW, water-cooling (FAC optional)					
Main Features	 Solder-free diode bar mounting technology, exclusive from MONOCROM S.L. The main features of the solder free concept of the clamp-mounting technology are: Long lifetime, due to the absence of the mechanical stress caused by the soldering process at high temperature. Minimum "smile", less than 0.5 im. High reliability in pulsed conditions, since the clamped bars do no suffer the same fatigue effect than the soldered ones due to the thermal cycle. Small thermal resistances, owing to the reduction of the contact resistance between electrodes and laser bar. No micro channels are needed to reach low thermal resistances. Large storage temperature interval tested from -60°C to + 85°C. Monocrom active mounting uses millimetre-water channels instead of microchannels. NORMAL WATER CAN BE USED FOR COOLING. No problems of obstruction or channel degradation exist. 					
Some Applications	 Extreme Environmental conditions –aeronautics, space, automotive industry– Pulsed-Energy mode –medicine, aesthetic, laser pumping– Material processing –fibre coupling, plastic and metallic industry, research– 					
Picture(s)						



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LBS-80A10-60QCW-2 GENERAL TECH SPECIFICATIONS						
Product number (according to type of diode)	LB-80A10-60QCW-2; 10 bars 808 nm, water cooled, 60em-270W bars, QCW operation					
Number of laser bars	10					
Number of emitters in each laser bar	60 – 75					
Laser bar geometry	1 cm wide emitter size: 110 – 150 μm e			80 – 90 % fill factor emitter spacing: 130 – 160 μm		
Center wavelength ⁽¹⁾	808 ± 3nm					
Output peak power,Pop, maximum (2)	2700					
Operation current (A), typical, lop	260A					
Threshold current (A)	30A					
TYP. OPERATION MODES						
Peak power, maximum	2700	2500	2000	1500		
Current (A), typ. for max. power	260	250	200	160		
Operation voltage (V), typ.	21,5	21	20	19		
Pulse length (ms), Max	1	5	10	20		
Duty cycle, Max	10	12	15	20		
Wavelength FWHM ⁽³⁾	2,5 nm					
Polarization	TM or TE					
Wavelength Temp. Coefficient	0,3 nm/⁰C					
Thermal resistance @ 1I/min (4)	0,085 °C/W					
Collimation	Cylindrical lenses on each diode bar, glued at the laser stack 5% power losses expected from lenses					
Beam divergence without collimation	Fast axis $\approx~35^{o},$ slow axis $\approx 10^{o}$					
Beam divergence with pre-collimation	Fast axis $\approx~$ 3-6 mrad, slow axis $\approx~10^{o}$					
Laser spot size after optics (Height x width)	23 x 11 mm					
Total stack size (Height x width x depths)	35x14x30 mm					
Cooling System	TAP water (distilled water with 5% ethylenglycol is recomm.)					
Water pressure	2-3 bars					
Water flow	>0,5 l/min					
Diode operation temperature, for max. Power	<25°C. If wet atmosphere, T>15°C is recommended					
Electrical connections	Fast connectors (Pin \varnothing 2x10mm), or threads M2mm					
Water connections	Water flow outlet for Ø3mm tube					
Water tubes	Rigid tube Øint.2mm / Øext.3mm					
Laser class product (EN-60825)	4					
Expected lifetime < 1ms		10 ⁹ pu	lses			

(1) Wavelengths from 780 to 1060 nm also available on request.

(2) Peak power before collimation lenses

(3) Spectral Width per bar. The total spectral width of the stack will depend on the center wavelength tolerance of the bars forming the stack, on duty cycle and pulse width.

(4) The module should be cooled properly to achieve these values

(5) Operation temperature could be increased for lower average power or QCW operation



Device sensitive to ESD & dust contamination => Handling under clean area conditions advised. Parametrical and dimensional specifications can be modified upon

request.

